



# 500V/5A Switching Regulator Applications

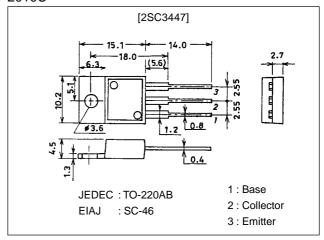
#### **Features**

- · High breakdown voltage and high reliability.
- · Fast switching speed ( $t_f$ : 0.1 $\mu$ s typ).
- · Wide ASO.
- · Adoption of MBIT process.

## **Package Dimensions**

unit:mm

2010C



### **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

| •                            |                  |                          |             |      |  |
|------------------------------|------------------|--------------------------|-------------|------|--|
| Parameter                    | Symbol           | Conditions               | Ratings     | Unit |  |
| Collector-to-Base Voltage    | V <sub>CBO</sub> |                          | 800         | V    |  |
| Collector-to-Emitter Voltage | V <sub>CEO</sub> |                          | 500         | V    |  |
| Emitter-to-Base Voltage      | V <sub>EBO</sub> |                          | 7           | V    |  |
| Collector Current            | lC               |                          | 5           | Α    |  |
| Collector Current (Pulse)    | I <sub>CP</sub>  | PW≤300μs, Duty Cycle≤10% | 10          | Α    |  |
| Base Current                 | I <sub>B</sub>   |                          | 2           | Α    |  |
| Collector Dissipation        | PC               | Tc=25°C                  | 50          | W    |  |
| Junction Temperature         | Tj               |                          | 150         | °C   |  |
| Storage Temperature          | Tstg             |                          | -55 to +150 | °C   |  |

#### Electrical Characteristics at Ta = 25°C

| Parameter                | Symbol            | Conditions                                 | Ratings |     |     | Unit |
|--------------------------|-------------------|--|---------|-----|-----|------|
|                          | Symbol            |  | min     | typ | max | Onit |
| Collector Cutoff Current | I <sub>CBO</sub>  | V <sub>CB</sub> =500V, I <sub>E</sub> =0   |         |     | 10  | μA   |
| Emitter Cutoff Current   | I <sub>EBO</sub>  | V <sub>EB</sub> =5V, I <sub>C</sub> =0     |         |     | 10  | μA   |
| DC Current Gain          | h <sub>FE</sub> 1 | V <sub>CE</sub> =5V, I <sub>C</sub> =0.6A  | 15*     |     | 50* |      |
|                          | h <sub>FE</sub> 2 | V <sub>CE</sub> =5V, I <sub>C</sub> =3A    | 8       |     |     |      |
| Gain-Bandwidth Product   | fT                | V <sub>CE</sub> =10V, I <sub>C</sub> =0.6A |         | 18  |     | MHz  |
| Output Capacitance       | C <sub>ob</sub>   | V <sub>CB</sub> =10V, f=1MHz               |         | 80  |     | pF   |

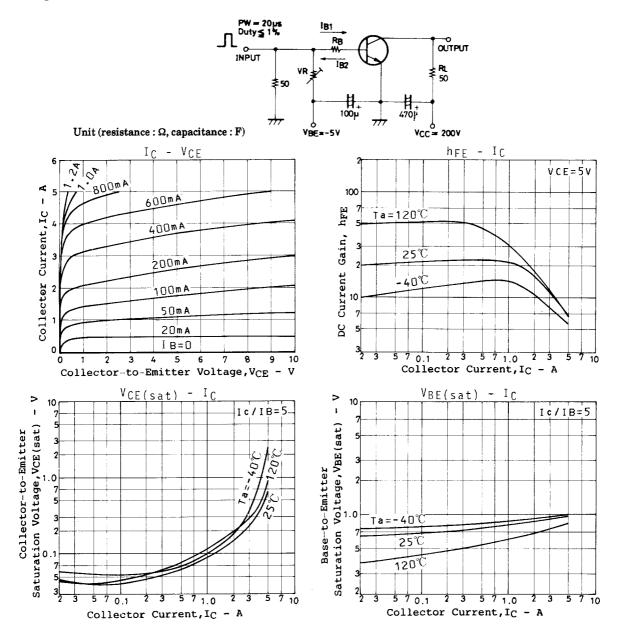
\*: The  $h_{FE}1$  of the 2SC3447 is classified as follows. When specifying the  $h_{FE}1$  rank, specify two ranks or more in principle.

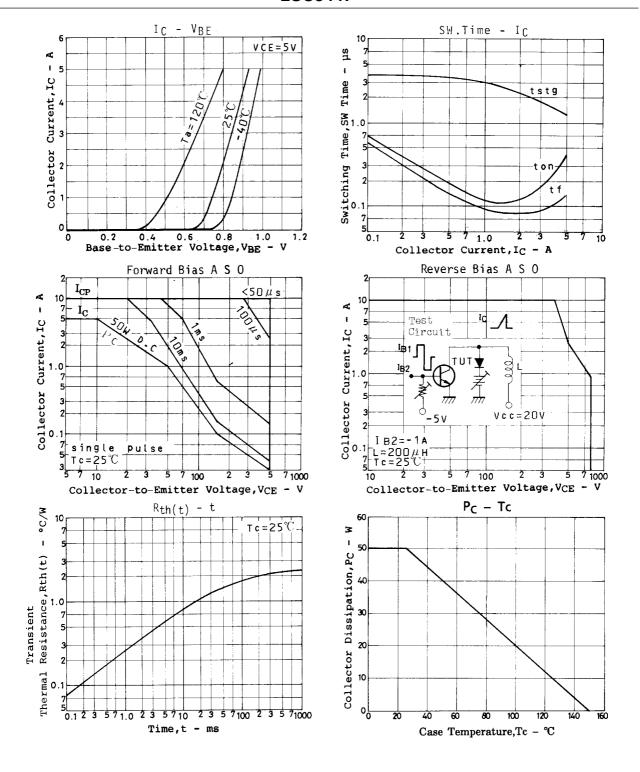
15 L 30 20 M 40 30 N 50

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| Parameter                               | Symbol                | Conditions   | Ratings |     |     | Unit |
|---|-----------------------|--|---------|-----|-----|------|
|   |                       |  | min     | typ | max | Unit |
| Collector-to-Emitter Saturation Voltage | V <sub>CE(sat)</sub>  | I <sub>C</sub> =3A, I <sub>B</sub> =0.6A                                     |         |     | 1.0 | V    |
| Base-to-Emitter Saturation Voltage      | V <sub>BE(sat)</sub>  | I <sub>C</sub> =3A, I <sub>B</sub> =0.6A                                     |         |     | 1.5 | V    |
| Collector-to-Base Breakdown Voltage     | V(BR)CBO              | I <sub>C</sub> =1mA, I <sub>E</sub> =0                                       | 800     |     |     | V    |
| Collector-to-Emitter Breakdown Voltage  | V(BR)CEO              | I <sub>C</sub> =5mA, R <sub>BE</sub> =∞                                      | 500     |     |     | V    |
| Emitter-to-Base Breakdown Voltage       | V(BR)EBO              | I <sub>E</sub> =1mA, I <sub>C</sub> =0                                       | 7       |     |     | V    |
| Collector-to-Emitter Sustain Voltage    | V <sub>CEX(sus)</sub> | I <sub>C</sub> =2.5A, I <sub>B1</sub> =-I <sub>B2</sub> =1A, L=1mH, clamped  | 500     |     |     | V    |
| Turn-ON Time                            | ton                   | $V_{CC}$ =200V, $5I_{B1}$ =-2. $5I_{B2}$ = $I_{C}$ =4A, $R_{L}$ = $50\Omega$ |         |     | 0.5 | μs   |
| Storage Time                            | t <sub>stg</sub>      | $V_{CC}$ =200V, $5I_{B1}$ =-2. $5I_{B2}$ = $I_{C}$ =4A, $R_{L}$ = $50\Omega$ |         |     | 3.0 | μs   |
| Fall Time                               | t <sub>f</sub>        | $V_{CC}$ =200V, $5I_{B1}$ =-2. $5I_{B2}$ = $I_{C}$ =4A, $R_{L}$ = $50\Omega$ |         |     | 0.3 | μs   |

### **Switching Time Test Circuit**





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